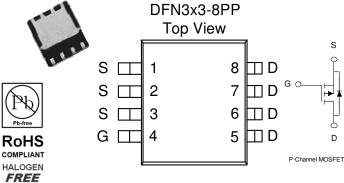
P-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low $r_{DS(on)}$ provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
-60	64 @ V _{GS} = -10V	-6.1			
	$109 @ V_{GS} = -4.5V$	-4.7			



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Maximum	Units				
Drain-Source Voltage		V_{DS}	-60	V			
Gate-Source Voltage	V_{GS}	±20	V				
	T _A =25°C] T	-6.1				
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-5	A			
Pulsed Drain Current ^b		I_{DM}	±30				
Continuous Source Current (Diode Conduction) ^a		I_S	-3.5	A			
D D: a	T _A =25°C	D	3.8	W			
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	PD	2.0	vv			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
a	t <= 10 sec	D	33	°C/W			
Maximum Junction-to-Ambient ^a	Steady State	$R_{ heta JA}$	81	°C/W			

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM7361P

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Conditions	Limits			Unit		
i didilietei	Symbol	rest conditions	Min	Тур	Max			
Static								
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \text{ uA}$	-1			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V$			±100	nA		
Zoro Goto Voltago Drain Current		$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$		-1				
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5	⊢ uA		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-20			Α		
Duain Caussa On Basistana A	r	$V_{GS} = -10 \text{ V}, I_D = -6.1 \text{ A}$			64	mO.		
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -4.7 \text{ A}$			109	mΩ		
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -6.1 \text{ A}$		11		S		
Diode Forward Voltage	V_{SD}	$I_S = 3.5 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		٧		
Dynamic ^b								
Total Gate Charge	Q_g	V 15 V V 4 5 V		15		nC		
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -6.1 \text{ A}$		4				
Gate-Drain Charge	Q_{gd}	I _D = -0.1 A		3				
Turn-On Delay Time	$t_{d(on)}$			12				
Rise Time	t _r	V_{DD} = -15 V , R_L = 6 Ω ,		9		nS		
Turn-Off Delay Time	$t_{d(off)}$	$I_D = -1 A$, $V_{GEN} = -10 V$		22				
Fall-Time	t _f			16		1		

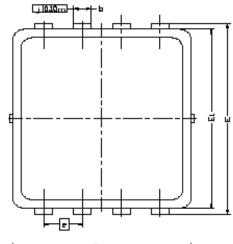
Notes

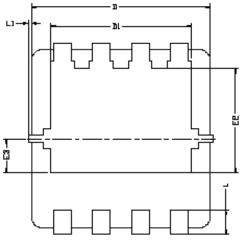
a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

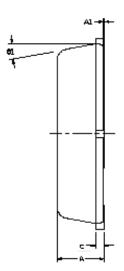
b. Guaranteed by design, not subject to production testing.

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Package Information







птм	MILLIMETERS			INCHES			
DIM.	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0,700	0'80	0,900	0.0276	0.0315	0.0354	
A1	0.00		0.05	0.000		0.002	
la	0.24	0.30	0.35	0.009	0.012	0.014	
C	0.10	0.152	0.25	0,004	0,006	0,010	
D	3.00 BSC			0.118 BSC			
D1	2.35 BCC			0.093 BSC			
Ε	3,20 BSC			0.126 BSC			
E1	3.00 BSC			0.118 BSC			
E5	1.75 BSC			0.069 BSC			
E3	0.575 BSC			0.023 BSC			
6	0.65 BSC			0.026 BSC			
L	0,30	0,40	0,50	0,0118	0.0157	0.0197	
L1			0.100	D		0.004	
Q1	0°	10*	12*	0*	10°	12*	